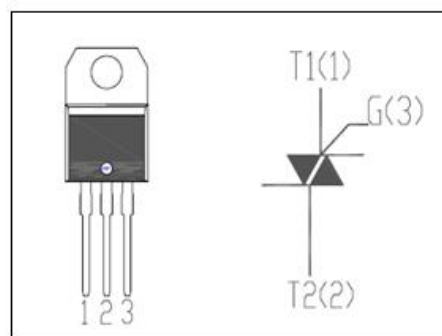


isc Triacs

BTA20-800B

FEATURES

- With TO-220AB insulated package
- Suitable for general purpose where high surge current capability is required. Application such as phase control and static switching on inductive or resistive load.



ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	MIN	UNIT
V _{DRM}	Repetitive peak off-state voltage	800	V
V _{RRM}	Repetitive peak off-state voltage	800	V
I _{T(RMS)}	RMS on-state current (full sine wave) T _j =70°C	20	A
I _{TSM}	Non-repetitive peak on-state current t _p =10ms	210	A
T _j	Operating junction temperature	125	°C
T _{stg}	Storage temperature	-40~150	°C
R _{th(j-c)}	Thermal resistance, junction to case	2.1	°C/W
R _{th(j-a)}	Thermal resistance, junction to ambient	60	°C/W

ELECTRICAL CHARACTERISTICS (T_c=25°C unless otherwise specified)

SYMBOL	PARAMETER		CONDITIONS	MAX	UNIT
I _{RRM}	Repetitive peak reverse current		V _R =V _{RRM} , T _j =25°C V _R =V _{RRM} , T _j =125°C	0.01 3.0	mA
I _{DRM}	Repetitive peak off-state current		V _D =V _{DRM} , T _j =25°C V _D =V _{DRM} , T _j =125°C	0.01 3.0	mA
I _{GT}	Gate trigger current	I	V _D =12V; R _L = 33 Ω	50	mA
		II		50	
		III		50	
		IV		100	
I _H	Holding current		I _{GT} = 0.5A, Gate Open	75	mA
V _{GT}	Gate trigger voltage all quadrant		V _D =12V; R _L = 33 Ω	1.5	V
V _{TM}	On-state voltage		I _T = 28A; t _p = 380 μs	1.7	V